

SPICE Device Model Si7633DP

Vishay Siliconix

P-Channel 20-V (D-S) MOSFET

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

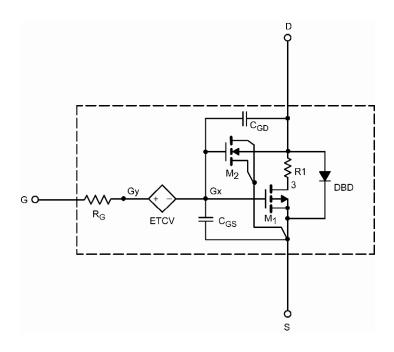
- · Apply for both Linear and Switching Application
- Accurate over the 55 °C to 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the $^{-}$ 55 $^{\circ}\mathrm{C}$ to 125 $^{\circ}\mathrm{C}$ temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25 °C UI	NLESS OTHERW	/ISE NOTED)			
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static	-				
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{_{DS}} = V_{_{GS}}, I_{_{D}} = -250 \ \mu A$	1.7		٧
Drain-Source On-State Resistance ^a	$R_{\scriptscriptstyle{DS(on)}}$	$V_{GS} = -10 \text{ V}, I_{D} = -20 \text{ A}$	0.0025	0.0027	Ω
		$V_{gs} = -4.5 \text{ V}, I_{D} = -15 \text{ A}$	0.0050	0.0044	
Forward Transconductance ^a	g_{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -20 \text{ A}$	57	80	S
Diode Forward Voltage	V _{SD}	I _s = - 5 A	- 0.72	- 0.74	٧
Dynamic ^b					
Input Capacitance	C _{iss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	9330	9500	pF
Output Capacitance	C _{oss}		1800	1830	
Reverse Transfer Capacitance	C _{rss}		1180	1740	
Total Gate Charge	Q _g	$V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -20 \text{ A}$	174	173	nC
		$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -20 \text{ A}$	90	85	
Gate-Source Charge	Q_{gs}		24	24	
Gate-Drain Charge	Q_{gd}		37	37	

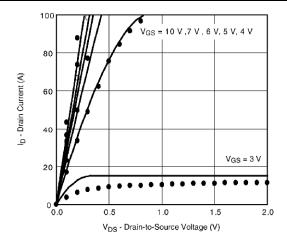
Notes

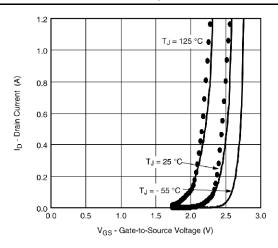
a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

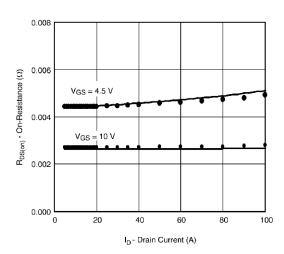


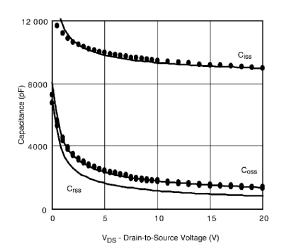
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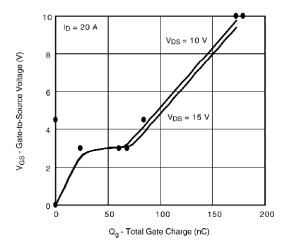
COMPARISON OF MODEL WITH MEASURED DATA (T, = 25 °C UNLESS OTHERWISE NOTED)

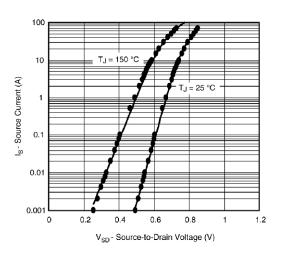












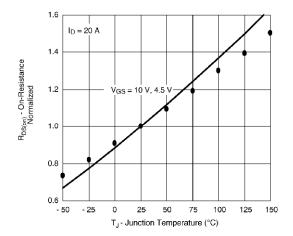
Note: Dots and squares represent measured data.

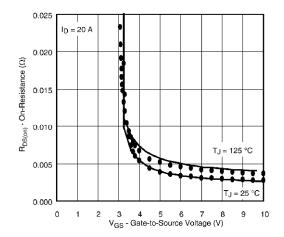
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COMPARISON OF MODEL WITH MEASURED DATA (T $_{\rm J}$ = 25 °C UNLESS OTHERWISE NOTED)







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